



# 10SQ030 THRU 10SQ100

## SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE -30 to 100Volts  
FORWARD CURRENT-10.0 Amperes

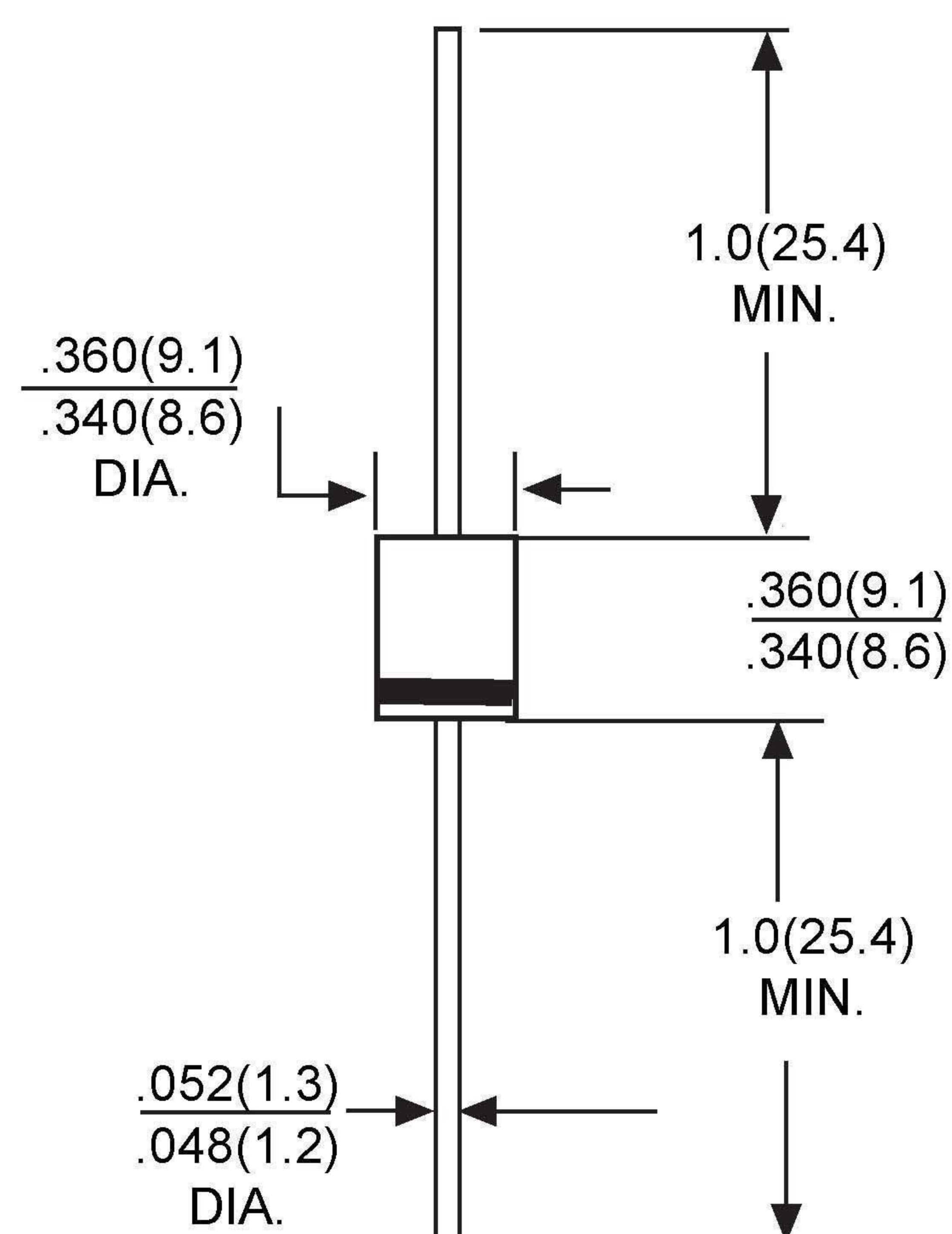
### Features

- \*Metal silicon rectifie,majority carrier conduction
- \*Guard ring for transient protection
- \*Low power loss,high efficiency
- \*High current capability,low VF
- \*High surge capacity
- \*Plastic package has UL flammability classification 94V-0
- \*For use low voltage,high frequency inverters,free wheeling,and polarity protection applications

### Mechanical Data

- \*Case:JEDEC R-6 Mo ded plastic
- \*Polarity:Color band cenotes cathode
- \*Weight:0.07 ounces 2.1 grams
- \*Mounting position:Any

### R-6



Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.  
Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%

Type Number	SYMBOL	10SQ030	10SQ035	10SQ040	10SQ045	10SQ050	10SQ060	10SQ080	10SQ100	UNIT	
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	30	35	40	45	50	60	80	100	V	
Maximum RMS Voltage	V <sub>RMS</sub>	21	24.5	28	31.5	35	42	56	70	V	
Maximum DC Blocking Voltage	V <sub>DC</sub>	30	35	40	45	50	60	80	100	V	
Maximum Average Forward Rectified Current@T <sub>A</sub> = 75°C	I <sub>F(AV)</sub>	10								A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Super imposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	275								A	
Peak Forward Voltage at 10A DC(Note1)	V <sub>F</sub>	0.55			0.7		0.8			V	
Maximun DC Reverse Current @ T <sub>j</sub> = 25°C at Rated DC Blocking Voltage @ T <sub>j</sub> = 100°C	I <sub>R</sub>	0.5				50					MA
Typical Junction Capacitance (Note 2)	C <sub>J</sub>	450								pF	
Typical Thermal Resistance (Note 3)	R <sub>θJC</sub>	3.0								°C/W	
Junction temperature- sperrschichttemperatue at reduced reverse voltage V <sub>R</sub> ≤ 80% V <sub>RRM</sub> bei reduzierter sperrspannung V <sub>R</sub> ≤ 50% V <sub>RRM</sub> in DC forward mode-bei Gleichstrom-Durchalss betrieb	T <sub>J</sub>	-55 to+150 ≤175 ≤200								°C	
Storage Temperature Range	T <sub>STG</sub>	-55 to+150									

NOTES: 1. 300us Pulse Width,2%Dudy Cyote.  
2.Measured at 1.0 MHZ and applied reverse voltage of 4.0VDC.  
3.Thermal Resistance Junction to Case.

# RATING AND CHARACTERISTIC CURVES 10SQ030 THRU 10SQ100



FIG.1- FORWARD CURRENT DERATING CURVE

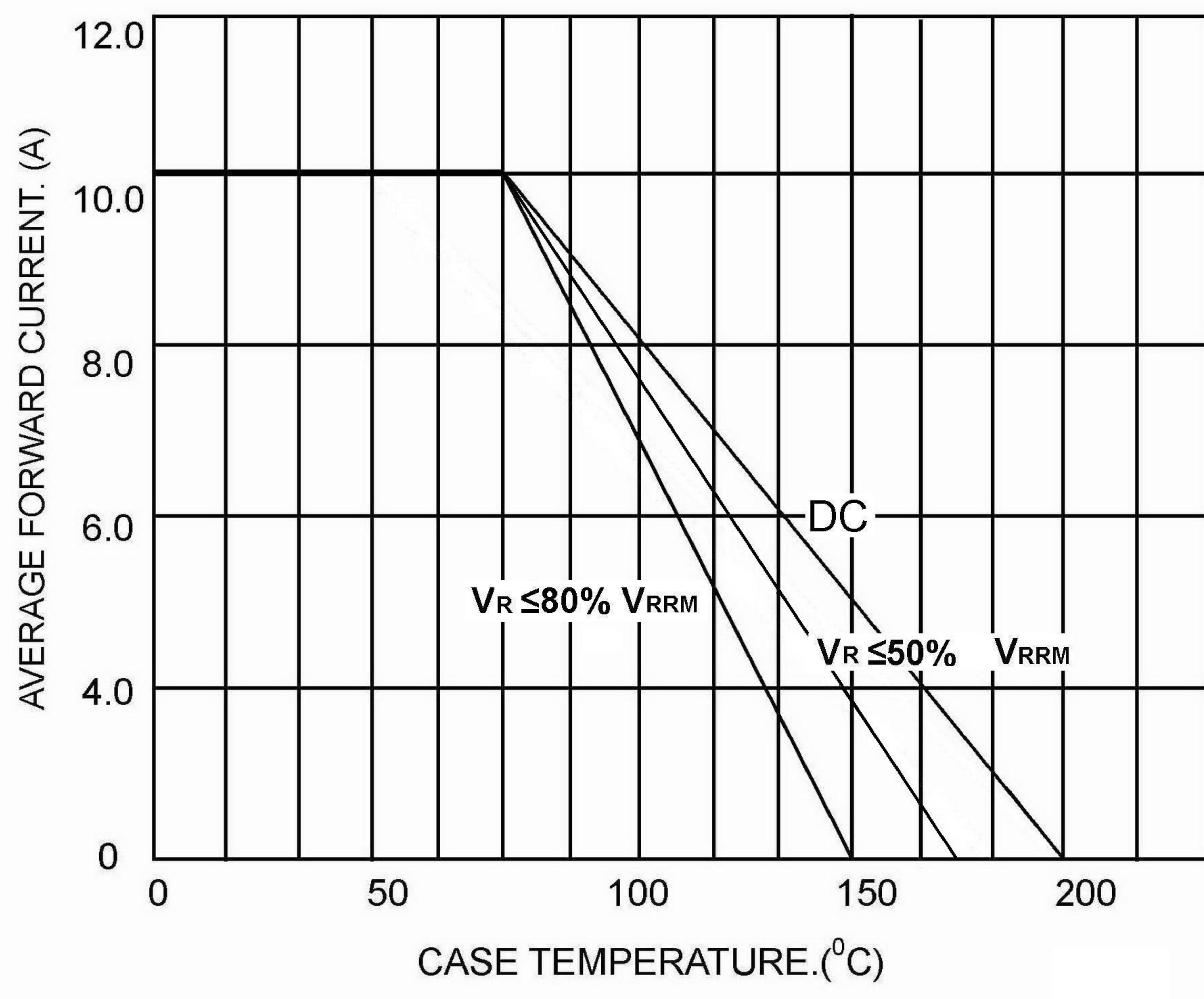


FIG.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

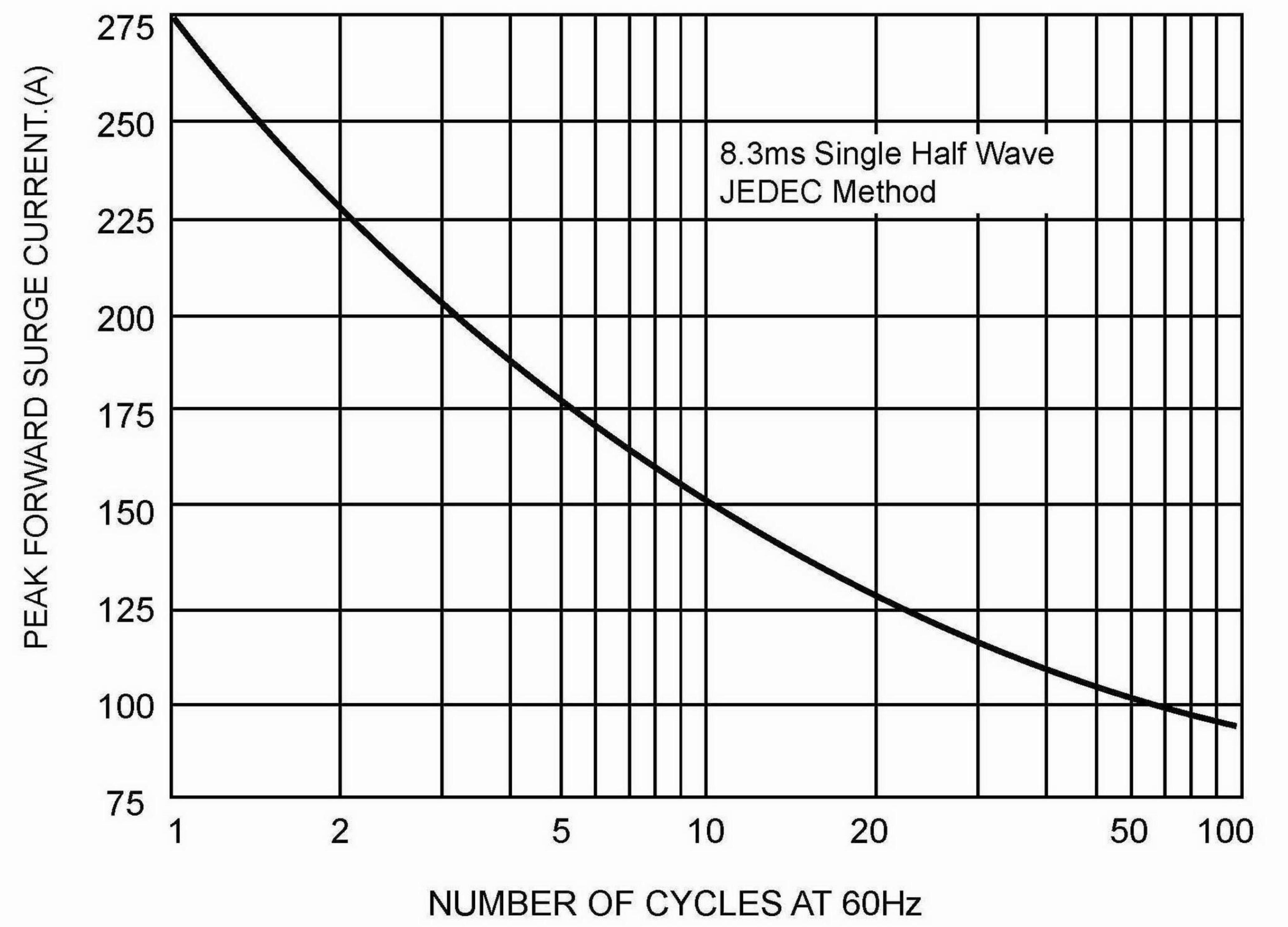


FIG.3-TYPICAL REVERSE CHARACTERISTIC

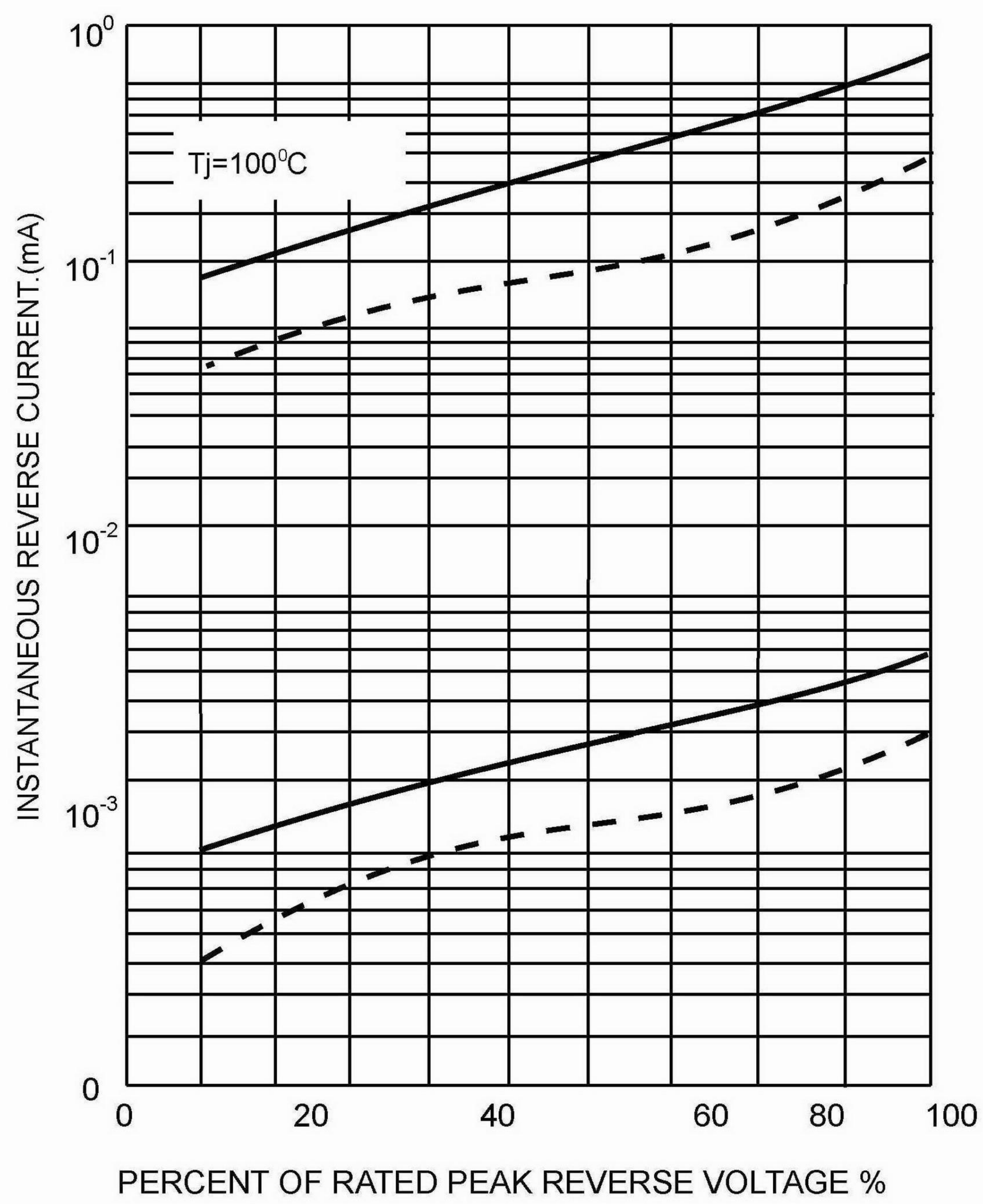


FIG.4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC

